

#### Description

The ECT34 10 is a 1.2M Hz constant frequency current mode PWM step-down converter. It is ideal for portable equipment requiring very high current up to 2A from single-cell Lithium-ion batteries while still achieving over 90% efficiency during peak load conditions. The ECT3410 also can run at 100% duty cycle for low dropout operation, extending battery life in portable systems while light load operation provides very low output ripple for noise sensitive applications.

The ECT3410 can supply up to 2A o utput load current from a 2.5V to 5.5V input voltage and the output voltage can be regulated as lo w as 0.6V. The high swit ching frequency minimizes the size of external components while keeping switching I osses low. The internal slope compensation setting all ows the device to operate with smaller indu ctor value s to optimize size and provide efficient operation.

The ECT3410 is available in adjustable (0.6V to  $V_{IN}$ ) and fixed (1.8V) output voltage versio ns. The d evice is available in a Pb-free, 3x3mm TDFN-10 package and is rated over the -40°C to+85°C temperature range.

#### Features

- Input Voltage Range: 2.5V to 5.5V
- Output Voltages from 0.6V to V<sub>IN</sub>
- 2A Output Current
- High Efficiency: Up to 95%
- 1.2MHz Constant Switching Frequency
- Low R<sub>DS(ON)</sub> Internal Switches: 0.15Ω
- Allows Use of Ceramic Capacitors
- Current Mode Operation for Excellent Line and Load Transient Response
- Short-Circuit and Thermal Fault Protection
- Soft Start
- Low Dropout Operation: 100% Duty Cycle
- Low Shutdown Current: I<sub>SHUTDOWN</sub> < 1μA
- Available is the Lead Free package

#### Applications

- Cellular Phones
- Digital Cameras
- DSP Core Supplies
- PDAs
- Portable Instruments
- Smart Phones



Block Diagram



## **Pin Assignment**



	Pin# S	ymbol	Function	
TDFN-10 (Top View)	1 EN		Enable pin. Active high. In shutdown, all functions are disabled drawing <1µA supply current. Do not leave EN floating.	
	2	IN	Power supply input pin. Must be closely decoupled to AGND with a $2.2\mu$ F or greater ceramic capacitor.	
	3	AIN	Analog supply input pin. Provides bias for internal circuitry.	
	4,6	AGND	Analog ground pin	
AGND 4 1 7 LX FB/ 5 6 AGN	5 FB	ίου τ	FB (ECT3410-ADJ): Adjustable Version feedback input pin. Connect FB to the center point of the external resistor divider. The feedback threshold voltage is 0.6V. OUT (ECT3408-B): Fixed version feedback input. Connect OUT to the output voltage, V <sub>OUT</sub> .	
	7,8	LX	Switching node pin. Connect the output inductor to this pin.	
	9,10	PGND	Power ground pin	
	_	EP	Power ground exposed pad. Must be connected to bare copper ground plane.	

**Ordering Information** 



### **Marking Information**

Package	Vout Voltage	Part Number	Marking	Marking Information
Al	ADJ	ECT3410-ADJ-FF	3410	XX is the outp ut volt age of production. Exam ple: Blank→Adjustable, 18→1.8V. YY is the year of p roduction. 08 means t he
TDFN-10	1.8V	ECT3410-18-FF	XX YYWW	product is manufactured in year of 2008. WW is the w eek of production. 25 means the Product is manufactured in the 25th week.



# Absolute Maximum Rating <sup>(1)</sup>

Parameter Sy	mbol	Value	Units
Input Supply Voltages	V <sub>IN</sub> ,V <sub>AIN</sub>	-0.3 to 6.0	V
FB, LX Voltages	V <sub>FB</sub> ,V <sub>LX</sub>	-0.3 to V <sub>IN</sub> + 0.3	V
EN Voltage	V <sub>EN</sub>	-0.3 to V <sub>IN</sub> + 0.3	V
Ground Voltages	PGND,AGND	-0.3 to 6.0	V
Operating Temperature Range	T <sub>A</sub>	-40 to +85	°C
Storage Temperature	T <sub>STG</sub>	-65 to 150	°C
Lead Temperature (Soldering, 10s)	T <sub>LEAD</sub>	300	°C

## Recommended Operating Conditions <sup>(3)</sup>

Parameter Sy	mbol	Value	Units
Thermal Resistance <sup>(2)</sup>	$\theta_{JA}$	45 °C/W	
Maximum Power Dissipation at $T_A = 25^{\circ}C$	P <sub>D</sub>	2.2 W	

Note:

(1). Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

(2). T<sub>J</sub> is calculated from the ambient temperature T<sub>A</sub> and power dissipation P<sub>D</sub> according to the following formula: T<sub>J</sub> = T<sub>A</sub> + P<sub>D</sub>  $x\theta_{JA}$ .

(3). Thermal resistance is specified with approximately 1 square inch of 1 oz copper.



## Electrical Characteristics<sup>1</sup>

 $V_{IN}$  = 3.6V,  $T_A$  = -40°C to +85°C unless otherwise noted; typical values are  $T_A$  = 25°C.

Description		Symbol	Conditions	Min	Тур	Max	Units
Input Voltage Range <sup>2</sup>		V <sub>IN</sub>	_	2.5		5.5	V
Output Voltage Range		V <sub>OUT</sub>	_	0.6		V <sub>IN</sub>	V
	Active Mode		VFB = 0.5V	—	300	500	μA
	Shutdown Mode	IQ	VFB = 0V, VAIN=5.5V	- 0.1		1	μA
Feedback Input Bias Curr	ent	I <sub>FB</sub>	VFB = 0.65V	—		30	nA
			TA = 25°C	0.5880	0.6000	0.6120	_
Regulated Feedback Volta	age <sup>3</sup>	V <sub>FB</sub>	0°C ≤ TA ≤ 85°C	0.5865	0.6000	0.6135	V
			-40°C ≤ TA ≤ 85°C	0.5850 0	.600 0	0.6150	
Line Regulation		$\frac{\Delta V_{\text{LINEREG}}}{\Delta V_{\text{IN}}}$	VIN = 2.5V to 5.5V, IOUT = 10mA	_	0.10	0.20	%/V
Load Regulation		$\frac{\Delta V_{\text{LOADREG}}}{\Delta I_{\text{OUT}}}$	IOUT = 10mA to 2000mA	_	0.20	—	%/A
Output Voltage Accuracy		V <sub>FB</sub>	VIN = 2.5 to 5.5V, IOUT = 10 to 2000mA	-3		+3	%
Oscillator Frequency		Fosc	V <sub>FB</sub> = 0.6V	0.96	1.2	1.44	MHz
Startup Time		Ts	From Enable to Output Regulation		1.3		ms
Over-Temperature Shutdown Threshold		T <sub>SD</sub>	—	_	170	_	°C
Over-Temperature Shutdo	own Hysteresis	T <sub>HYS</sub>	—	_	10		°C
Peak Switch Current		I <sub>LIM</sub>	—	2.5	3.5		А
P-CH MOSFET		R <sub>DS(ON)</sub>	VIN = 3.6V	— 135		200	
N-CH MOSFET			VIN = 3.6V	— 95		150	11122
Enable Threshold Low		V <sub>EN(L)</sub>	-	_		0.3	V
Enable Threshold High		V <sub>EN(H)</sub>	_	1.5			V
Input Low Current		I <sub>EN</sub>	VIN = VEN = 5.5V	-1.0		1.0	μΑ

Note:

1. The ECT3410 is guaranteed to meet performance specifications over the -40°C to +85°C operating temperature range and is assured by design, characterization, and correlation with statistical process controls.

2.  $V_{IN}$  should be not less than  $V_{OUT} + V_{DROPOUT}$ , where  $V_{DROPOUT} = I_{OUT} \times (R_{DS (ON) PMOS} + ESR_{INDUCTOR})$ , typically  $V_{DROPOUT} = 0.3V$ .

3. The regulated feedback voltage is tested in an internal test mode that connects  $V_{FB}$  to the output of the error amplifier.



### **Typical Performance Characteristics**





### **Typical Performance Characteristics (Continued)**





Quiescent Current vs. Input Voltage ( $T_A = 25^{\circ}C, L = 2.2\mu H, C_{IN} = C_{OUT} = 22\mu F$ )



Quiescent Current vs. Temperature (L =  $2.2\mu$ H, C<sub>IN</sub> = C<sub>OUT</sub> =  $22\mu$ F)







### **Typical Performance Characteristics (Continued)**



P-Channel R<sub>DS(ON)</sub> vs. Input Voltage

N-Channel R<sub>DS(ON)</sub> vs. Input Voltage



Switching Frequency vs. Temperature (V<sub>IN</sub> = 3.6V; V<sub>OUT</sub> = 1.8V)



Soft Start (V<sub>IN</sub> = 3.6V; V<sub>OUT</sub> = 1.8V; I<sub>OUT</sub> = 2A; C<sub>FF</sub> = 22pF)



Reference Voltage vs. Temperature (V<sub>IN</sub> = 3.6V)



Load Transient Response (V<sub>IN</sub> = 3.6V; V<sub>OUT</sub> = 1.8V; L = 2.2µH; C<sub>IN</sub> = C<sub>OUT</sub> = 22µF)





## **Typical Performance Characteristics (Continued)**





### **Functional Description**

The ECT3410 is a high output current monolithic switch-mode step-down DC-DC converter. The device operates at a fixed 1.2MHz switching frequency, and uses slope compensated current mode architecture. This step down DC-DC converter can sup ply up to 2A output current at  $V_{IN}$  = 3V and has an input voltage range from 2.5V to 5.5V. It minimizes external com ponent size and optimizes efficiency at the heavy lo ad range. The slope compensation allows the device to remain stable over a wider range of inductor values so that smaller values (1µH to 4.7µH) with lower DCR can be used to achieve higher efficiency. Apart from the small bypass input capacitor, only a small L-C filter is required at the output. The fixed output version requires only three external power components ( $C_{IN}$ ,  $C_{OUT}$ , and L). The adjustable version can be programmed with external feedback to any voltage, ranging from 0.6V to near the input voltage. It uses internal MOSFETs to achieve high efficiency and can generate very low output voltages by using an internal reference of 0.6V. At dropout, the conv erter duty cycle increases to100% and the output voltage tracks the input voltage minus the low  $R_{DS (ON)}$  drop of the P-channel high-side MOSFET and the inductor DCR. The Internal error a mplifier and compensation provides excellent transient response, lo ad and line regulation. Internal soft start eliminates any output voltage overshoot when the enable or the input voltage is applied.

#### **Current Mode PWM Control**

Slope compensated current mode PWM control provides stable switching and cycl e-by-cycle current limit for excellent load and line response and protection of the internal main switch (P-channel MOSFET) and synchronous rectifier (N-channel MOSFET). During normal operation, the internal P-channel MOSFET is turned on for a specified time to ram p the inductor current at each rising edge of the internal oscillator, and is switched off when the peak inductor current is above the error voltage. The current comparator,  $I_{COMP}$ , limits the peak inductor current. When the main switch is off, the synchronous rectifier turns on immediately and stays on until either the inductor current starts to reverse, as indicated by the current reversal comparator,  $I_{ZERO}$ , or the beginning of the next clock cycle.

#### Control Loop

The ECT3410 is a peak current mode step-down converter. The current through the P-channel MOSFET (high side) is sensed for current loop control, as well as sho rt circuit and overload protection. A slope compensation signal is added to the sen sed current to maintain stability for dut y cycles greater than 50%. The peak current mode loop appears as a voltage-programmed current source in parallel with the output capacitor. The output of the voltage error amplifier programs the current mode loop for the necessary peak switch current to force a constant output voltage for all load a nd line condition s. Internal I oop compensation terminates the T ran conductance voltage error amplifier output. For fixed voltage versions, the error amplifier reference voltage is internally set to p rogram the converter output voltage. For the adjustable output, the error amplifier reference is fixed at 0.6V.

#### Soft Start / Enable

Soft start limits the current surge seen at the input and eliminates output voltage overshoot. The enable pin is active high. When pulled low, the enable input (EN) forces the ECT3410 into a low-power, non-switching state. The total input current during shutdown is less than  $1\mu$ A.

#### **Current Limit and Over-Temperature Protection**

For overload conditions, the peak input current is limited to 3.5A. To minimize power dissipation and stresses under current limit and short-circuit conditions, switching is terminated after entering current limit for a series of pulses. The termination lasts for seven consecutive clock cycles after a current limit has been sensed during a series of four consecutive clock cycles.

Thermal protection completely disables switching when internal dissipation becomes excessive. The junction over-temperature thre shold is 170 °C with 10°C of hysteresis. Once an over-temperature or over-current fault conditions is removed, the output voltage automatically recovers.

#### **Dropout Operation**

When the battery input voltage decreases near the value of the output voltage, the ECT3410 allows the main switch to remain on for more than one switching cycle and increases the duty cycle until it reaches 100%.

The duty cycle D of a step-down converter is defined as:

$$D = T_{ON} * F_{OSC} * 100\% \approx \frac{V_{OUT}}{V_{IN}} * 100\%$$

Where  $T_{\text{ON}}$  is the main switch on time and  $F_{\text{OSC}}$  is the oscillator frequency.

The output voltage then is the input voltage minus the voltage drop across the main switch and the inductor. At low input supply voltage, the  $R_{DS (ON)}$  of the P-channel MOSFET increases and the efficiency of the converter decreases. Caution must be exercised to ensure the heat dissipated does not exceed the maximum junction temperature of the IC.

#### **Maximum Load Current**

The ECT3410 will o perate with a n in put su pply voltage as low as 2.5V; however, the maximum lo ad current decreases at lower input due to the large I R d rop on t he m ain switch and syn chronous rectifier. The sl ope compensation sign al red uces the peak inductor current as a function of the duty cycle to prevent sub -harmonic oscillations at duty cycles greater than 50%. Conversely, the current limit increases as the duty cycle decreases.

ECT3410

#### **Applications Information**



Figure1: Basic Application Circuit for the Adjustable Output Version.



Figure2: Basic Application Circuit for the Fixed Output Versions



### Setting the Output Voltage

Figure 1 shows the basic application circuit with the ECT3410 adj ustable o utput version while Figure 2 shows the application circuit with the ECT3410 fixed output version. For applications requiring an adjustable output voltage, the ECT3410 adjustable version can be externally programmed. Resistors R1 and R2 in Figure 1 program the output to regulate at a voltage higher than 0.6V. To limit the bias current required for the external feedback resistor string while maintaining good noise immunity, the minimum suggested value for R2 is  $59k\Omega$ . Although a larger value will further reduce quiescent current, it will also increa se the im pedance of the feedback node, making it more sensitive to external noise and interference. Table 1 summarizes the resistor values for various output voltages with R2 set to either  $59k\Omega$  for good noise immunity or  $316k\Omega$  for reduced no load input current.

The adjustable version of the ECT3410, combined with an external feed forward capacitor (C3 in Figure 1), delivers enhanced transient response for extre me pulsed load applications. The a ddition of the feed forward capacitor typically requires a larger output capacitor C2 for stability. The external resistor sets the output voltage according to the following equation:

$$V_{OUT} = 0.6V * \left[ 1 + \frac{R1}{R2} \right]$$
 or  $R1 = \left[ \left( \frac{V_{OUT}}{0.6V} \right) - 1 \right] * R2$ 

V <sub>оит</sub> (V)	R1=59K R2 (KΩ) R1	=316Κ R2(ΚΩ)
0.8 19.6		105
0.9 29.4		158
1.0 39.2		210
1.1 49.9		261
1.2 59.0		316
1.3 68.1		365
1.4 78.7		422
1.5 88.7		475
1.8 118		634
1.85 124		655
2.0 137		732
2.5 187		1000
3.3 267		1430

Table1. Resistor Selection for Output Voltage Setting; Standard 1% Resistor Values Substituted Closest to the Calculated Values.



#### Inductor Selection

For most designs, the ECT3410 operates with inductor values of  $1\mu$ H to  $4.7\mu$ H. Low inductance values are physically smaller, but require faster switching, which results in some efficiency loss. The inductor value can be derived from the following equation:

$$L = \frac{V_{OUT} * (V_{IN} - V_{OUT})}{V_{IN} * \Delta I_{L} * f_{osc}}$$

Where  $\Delta I_{L}$  is inductor ripple current. Large value in ductors lower ripple current and small value inductors result in high ripple currents. Choose inductor ripple current approximately 30% of the maximum load current 2A, or

For output voltages above 2.0V, when light-load efficiency is important, the minimum recommended inductor is 2.2µH Manufacturer's specifications list both t he inductor DC current rating, which is a thermal limit ation and the peak current rating, which is determined by the saturation characteristics. The inductor should not show any appreciable saturation under normal load conditions. Some inductors may meet the peak and average current ratings yet result in excessive losses due to a high DCR.

Always consider the losses associated with the DCR and its effect on the total converter efficiency when selecting an inductor. For optimum voltage- positioning load transients, choose an inductor with DC series resistance in the  $20m\Omega$  to  $100m\Omega$  range. F or h igher efficiency at hea vy loads (above 200mA), or minimal load regulation (but som e transient overshoot), the resistance should be kept below  $100m\Omega$ . The DC current rating of the inductor should be at least equal to the maxim um load current plus half the ripple current to prevent core saturation (2A + 600mA). Table 2 lists some typical surface mount inductors that meet target applications for the ECT3410.

For example, the 2.2 $\mu$ H CDRH5D16-2R2 inductor selected from Sumida has a 28.7m $\Omega$  DCR and a 3.0 ADC current rating. At full load, the inductor DC loss is 57m W which gives a 1.6% loss in efficiency for a 1200mA, 1.8V output.

Manufacturer	Part Number	Inductance (µH)	Max DC Current (A)	DCR (mΩ)	Size (mm) LxWxH	Туре
	CDRH5D16	2.2	3.0	28.7	E 94E 941 9	Shielded
Sumua		3.3	2.6	35.6	0.0X0.0X1.0	
Sumida	CDRH8D28	4.7	3.4	19	8.3x8.3x3.0	Shielded
Coiltronics	SD53	2.0	3.3	23	5.2x5.2x3.0	Shielded
		3.3	2.6	29		
		4.7	2.1	39		
Manufacturer	er Part Number		Value	Voltage (V)	Temp. C o.	Case
Murata	GRM219R60J106KE19		10µF	6.3	X5R	0805
Murata	GRM21BR60J226ME39		22µF	6.3	X5R	0805
Murata	GRM1551X1E220JZ01B		22pF	25	JIS	0402

Table2. Suggested Component Selection Information



#### Input Capacitor Selection

The input capacitor reduces the surge current drawn from the input and switching noise from the device. The input capacitor impedance at the switching frequency should be I ess than the input source impedance to prevent high frequency switching current passing to the input. The calculated value varies with input voltage and is a maximum when  $V_{IN}$  is double the output voltage.

$$C_{IN} = \frac{\frac{V_O}{V_{IN}} * \left(1 - \frac{V_O}{V_{IN}}\right)}{\left(\frac{V_{PP}}{I_O} - ESR\right) * f_S}$$
$$C_{IN(MIN)} = \frac{1}{\left(\frac{V_{PP}}{I_O} - ESR\right) * 4 * f_S}$$

A low ESR input capacitor sized for maximum RMS current must be use d. Ceramic cap acitors with X5R or X7R dielectrics are highly recommended because of their low ESR and small temperature coefficients. A 22µF ceramic capacitor for most applications is sufficient. A large value may be used for improved input voltage filtering.

The maximum input capacitor RMS current is:

$$I_{\text{RMS}} = I_{\text{O}} \cdot \sqrt{\frac{V_{\text{O}}}{V_{\text{IN}}} \cdot \left(1 - \frac{V_{\text{O}}}{V_{\text{IN}}}\right)}$$

The input capacitor RMS ipple current varies with the input and output voltage and will always be less than or equal to half of the total DC load current

$$I_{RMX(MAX)} = \frac{I_o}{2}$$

To minimize stray inductance, the capacitor should be placed as closely as possible to the IC. This keeps the high frequency content of the i nput current localized, minimizing EMI and input voltage ripple. A laboratory test set-up typically consists of two long wires running from the bench power supply to the evaluation board input voltage pins. The inductance of these wires, along with the low-ESR ceramic input capacitor, can create a high Q net- work that may affect converter performance. This problem often becomes apparent in the form of exce ssive ringing in the output voltage during load transients. Errors in the loop phase and gain measurements can also result.

Since the inductance of a short PCB trace feeding the input voltage is significantly lower than the power leads from the bench power supply, most applications do not exhibit this problem. In applications where the input power source lead inductance cannot be reduced to a level that does not affect the converter performance, a high ESR tantalum or aluminum electrolytic should be placed in parallel with the low ESR, ESL bypass ceramic.

This dampens the high Q network and stabilizes the system.



### **Output Capacitor Selection**

The function of output capacitance is to store energy to attempt to maintain a constant voltage. The energy is stored in the capacitor's electric field due to the voltage applied.

The value of output capa citance is ge nerally selected to limit o utput voltage ripple to the level require d by the specification. Since the ripple current in the output inductor is usually determined by L, V<sub>OUT</sub> and V<sub>IN</sub>, the series impedance of the capacitor primarily determines the output voltage ripple. The three elements of the capacitor that contribute to its impedance (and output voltage ripple) are equivalent series resistance (ESR), equivalent series inductance (ESL), and capacitance (C).

The output voltage droop due to a load transient is dominated by the capacitance of the ceramic out- put capacitor. During a step increase in I oad current, the ce ramic output capacitor alone supplies the load current until the loop responds. Wi thin two swit ching cycles, the loop respond s and the inductor current increases to match the load current demand. The relation ship of the output voltage droop during the two switching cycles to the output capacitance can be estimated by:

$$C_{OUT} = \frac{3 * \Delta I_{LOAD}}{V_{DROOP} * f_s}$$

In many practical designs, to get the required ESR, a capacitor with much more capacitance than is needed must be selected.

For both continuous and discontinuous inductor current mode operation, the ESR of the  $C_{OUT}$  needed to limit the ripple to  $\Delta V_0$ , V peak-to-peak is:

$$ESR \leq \frac{\Delta V_0}{\Delta I_L}$$

Ripple current flowing through a cap acitor's ESR causes power dissipation in the cap acitor. This power dissipation causes a temperature increase internal to the capacitor. Excessive temperature can seriously shorten the expected life of a cap acitor. Capacitors have rippled current ratings that are dependent on ambient temperature and should not be exceeded. The output capacitor ripple current is the inductor current,  $I_L$ , minus theoutput current,  $I_O$ . The RMS value of the ripple current flowing in the output capacitance (continuous inductor current mode operation) is given by:

$$I_{RMS(MAX)} = \frac{\sqrt{3}}{6} = \Delta I_L * 0.289$$

ESL can be a problem by causing ringing in the low megahertz region but can be controlled by choo sing low ESL capacitors, limiting lead I ength (P CB and capacitor), and replacing one large device with several smaller ones connected in parallel.

In con clusion, in order to meet the requirement of output volt age ripple small and regulation loop stability, ceramic capacitors with X5R or X7R dielectrics are recommended due to their low ESR and high ripple current ratings. The output rippl e  $V_{OUT}$  is determined by:

$$\Delta V_{OUT} \le \frac{V_{OUT} * (V_{IN} - V_{OUT})}{V_{IN} * f_{osc} * L} * \left( ESR + \frac{1}{8 * f_{OSC} * C_{OUT}} \right)$$

A 22 $\mu$ F ceramic capacitor can satisfy most applications.



#### Slope Compensation

The ECT34 10 step-d own converter uses peak current mode control with a unique ada ptive slope compensation scheme to maintain stability with lower value inductors for duty cycles greater than 50%. The slope compensation is set to maintain stability with lower value inductors which provide better overall efficiency. The output inductor value must be selected so the inductor current down slope meets the internal slope compensation requirements. As an example, the value of the slope compensation is set to  $1A/\mu s$  which is large enough to guarantee stability when using a  $2.2\mu$ H inductor for all output voltage levels from 0.6V to 3.3V.

The worst case external current slope (m) using the  $2.2\mu$ H inductor is when V<sub>OUT</sub> = 3.3V and is:

$$m = \frac{V_{OUT}}{L} = \frac{3.3}{2.2} = 1.5 A / \mu s$$

To keep the power supply stable when the duty cycle is above 50%, the intern al slope compensation (mA) should be:

$$m_a \ge \frac{1}{2} * m = 0.75 A / \mu s$$

Therefore, to guarantee current loop stability, the slope of the compensation ramp must be greater than one-half of the down slope of the current waveform. So the internal slope compensated value of  $1A/\mu s$  will guarante e stability using a  $2.2\mu$ H inductor value for all output voltages from 0.6V to 3.3V.

#### **Thermal Calculations**

There are three types of losses associated with the ECT3410 step-down converter: switching losses, conduction losses, and quiescent current losses. Conduction losses are associated with the  $R_{DS(ON)}$  characteristics of the power output switching devices. Switching losses are dominated by the gate charge of the power output switching. At full load, assuming continuous conduction mode (CCM), a simplified form of the losses is given by

$$P_{TOTAL} = \frac{I_o^{2} * (R_{DSON(HS)} * V_o + R_{DSON(LS)} * [V_{IN} - V_o])}{V_{IN}}$$

 $I_Q$  is the step-down converter quiescent current. The term  $t_{sw}$  is us ed to estimate the full load step-down converter switching losses.

For the condition where the step-down converter is in dropout at 100% duty cycle, the total device dissipation reduces to:

$$P_{TOTAL} = I_O^2 * R_{DSON(HS)} + I_Q * V_{IN}$$

Since  $R_{DS (ON)}$ , quiescent current and switching losses all vary with input voltage, the total losses should be investigated over the complete input voltage range. Given the total losses, the maximum junction temperature can be derived from the  $\theta_{JA}$  for the TDFN-10 package which is 45°C/W.

$$T_{J(MAX)} = P_{TOTAL} * \theta_{JA} + T_{AMB}$$

## Step-Down Converter Design Example Specifications

 $V_o = 1.8V @ 2A$   $V_{IN} = 2.7V$  to 4.2V (3.6V nominal)  $f_s = 1.2MHz$ Transient droop = 200mV  $\Delta V_o = 50mV$ 

## **1.8V Output Inductor**

 $\Delta I_{L} = 30\% \cdot I_{O} = 0.3 \cdot 2 = 600 \text{mA}$ 

$$L = \frac{V_{\text{OUT}} \cdot (V_{\text{IN(MAX)}} - V_{\text{OUT}})}{V_{\text{IN(MAX)}} \cdot \Delta I_{\text{L}} \cdot f_{\text{OSC}}} = \frac{1.8 \cdot (4.2 - 1.8)}{4.2 \cdot 0.6 \cdot 1.2 \cdot 10^{6}} = 1.4 \mu \text{H}$$

For Sumida 2.2µH inductor (CDRH2D14) with DCR  $75m\Omega,$  the  $\Delta I_{\scriptscriptstyle L}$  should be:

$$\Delta I_{L} = \frac{V_{O}}{L} \cdot \left(1 - \frac{V_{O}}{V_{IN}}\right) \cdot T = 395 \text{mA}$$

$$I_{PKL} = I_0 + \frac{\Delta I_L}{2} = 2 + \frac{0.395}{2} = 2.2A$$

 $P_{L} = I_{0}^{2} \cdot DCR = 2^{2} \cdot 0.0287 = 114.8 mW$ 

## 1.8V Output Capacitor

$$C_{OUT} = \frac{3 \cdot \Delta I_{LOAD}}{V_{DROOP} \cdot f_{S}} = \frac{3 \cdot 1.2}{0.2 \cdot 1.2 \cdot 10^{6}} = 25 \mu F; \text{ use } 22 \mu F$$

$$\mathsf{ESR} \le \frac{\Delta \mathsf{V}_{\mathsf{O}}}{\Delta \mathsf{I}_{\mathsf{L}}} = \frac{0.05}{0.395} = 0.13\Omega$$

Select a 22 $\mu\text{F},\,10\text{m}\Omega$  ESR ceramic capacitor to meet the ripple 50mV requirement.

$$\begin{split} \Delta V_{\text{OUT}} &\leq \frac{V_{\text{OUT}} \cdot (V_{\text{IN}} - V_{\text{OUT}})}{V_{\text{IN}} \cdot f_{\text{OSC}} \cdot L} \cdot \left( \text{ESR} + \frac{1}{8 \cdot f_{\text{OSC}} \cdot C_{\text{OUT}}} \right) \\ &= \frac{1.8 \cdot (4.2 - 1.8)}{4.2 \cdot 1.2 \cdot 10^6 \cdot 2.2 \cdot 10^{-6}} \cdot \left( 0.01 + \frac{1}{8 \cdot 1.2 \cdot 10^6 \cdot 22 \cdot 10^{-6}} \right) = 5.7 \text{mV} \end{split}$$

 $I_{RMS} = \Delta I_L \cdot 0.289 = 0.395 \cdot 0.289 = 114 mArms$  $P_{COUT} = ESR \cdot I_{RMS}^2 = 0.01 \cdot 1^2 = 10 mW$ 



## **Input Capacitor**

Input ripple  $V_{PP} = 25mV$ 

$$C_{\text{IN(MIN)}} = \frac{1}{\left(\frac{V_{\text{PP}}}{I_0} - \text{ESR}\right) \cdot 4 \cdot f_s} = \frac{1}{\left(\frac{0.025}{2} - 0.01\right) \cdot 4 \cdot 1.2 \cdot 10^6} = 13.9 \mu\text{F}; \text{ use } 22 \mu\text{F}$$

 $I_{RMS} = \frac{10}{2} = \frac{2}{2} = 1$  Arms

 $\mathsf{P}_{\mathsf{CIN}} = \mathsf{ESR} \cdot \mathsf{I}_{\mathsf{RMS}}{}^2 = 0.01 \cdot 1^2 = 10 \mathsf{mW}$ 

#### ECT3410 Losses

 $\mathsf{P}_{\mathsf{TOTAL}} = \mathsf{I}_{\mathsf{O}}^2 \cdot \mathsf{R}_{\mathsf{DS}(\mathsf{ON})\mathsf{P}} \cdot \mathsf{D} + \mathsf{I}_{\mathsf{O}}^2 \cdot \mathsf{R}_{\mathsf{DS}(\mathsf{ON})\mathsf{N}} \cdot (\mathsf{1-D}) + (\mathsf{t}_{\mathsf{SW}} \cdot \mathsf{f}_{\mathsf{S}} \cdot \mathsf{I}_{\mathsf{O}}) \cdot \mathsf{V}_{\mathsf{IN}}$ 

$$= 2^{2} \cdot 0.135 \cdot \frac{1.8}{4.2} + 2^{2} \cdot 0.095 \cdot \left(1 - \frac{1.8}{4.2}\right) + (5 \cdot 10^{-9} \cdot 1.2 \cdot 10^{6} \cdot 2) \cdot 4.2 = 498.9 \text{mW}$$



## Mechanical Dimensions OUTLINE DRAWING TDFN-10



Top View





DIMENSIONS						
DIMN	INC	HES	MM			
	MIN MA	х	MIN	MAX		
A 0.1	16	0.119	2.95	3.05		
B 0.1	16	0.119	2.95	3.05		
C 0.06	5	0.069	1.65	1.75		
D 0.09	3	0.096	2.35	2.45		
b 0.00	7	0.011	0.18	0.28		
e 0.02	þ		0.500 BSC			
L 0.01	4	0.018	0.35	0.45		
A1 0.02	.8	0.031	0.70	0.80		
A2 0.00	0	0.004	0.00	0.10		
A3 0.00	8		0.20	3REF		